NSN 5961-01-294-9623

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-9623 **Inclosure Material:** Glass **Overall Length:** Between 0.145 inches and 0.165 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.068 inches and 0.075 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 0.3 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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